



Micro Commercial Components



Micro Commercial Components  
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# MCM1206

## P-Channel Power MOSFET

### Features

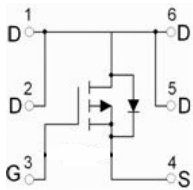
- Advanced trench MOSFET process technology
- Ultra low on-resistance with low gate charge
- Halogen free available upon request by adding suffix "-HF"
- Epoxy meets UL 94 V-0 flammability rating
- Moisture Sensitivity Level 1
- Marking:1206

### Maximum Ratings @ 25°C Unless Otherwise Specified

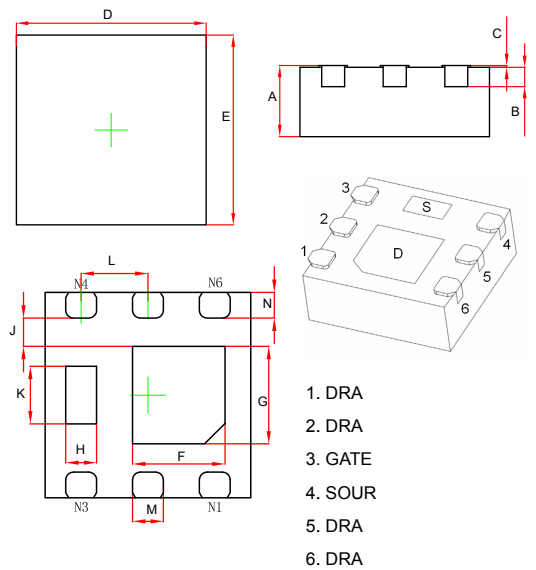
Symbol	Parameter	Rating	Unit
$V_{DS}$	Drain-source Voltage	-12	V
$I_D$	Drain Current-Continuous	-6	A
$I_{DM}$	Pulsed Drain Current (note1)	-20	A
$V_{GS}$	Gate-source Voltage	$\pm 8$	V
$R_{\theta JA}$	Thermal Resistance Junction to Ambient(note1)	357	$^{\circ}C/W$
$T_J$	Operating Junction Temperature	-55 to +150	$^{\circ}C$
$T_{STG}$	Storage Temperature	-55 to +150	$^{\circ}C$

(1).Repetitive rating:Pluse width limited by junction temperature

### Equivalent Circuit



### DFN2020-6J



DIM	INCHES		MM		NOTE
	MIN	MAX	MIN	MAX	
A	0.028	.032	0.700	0.800	
B	0.008REF.		0.203REF.		
C	0.000	0.002	0.000	0.050	
D	0.076	0.082	1.924	2.076	
E	0.076	0.082	1.924	2.076	
F	0.031	0.039	0.800	1.000	
G	0.033	0.041	0.850	1.050	
H	0.008	0.016	0.200	0.400	
J	0.008	---	0.200	---	
K	0.018	0.026	0.460	0.660	
L	0.026TYP.		0.650TYP.		
M	0.010	0.014	0.250	0.350	
N	0.007	0.013	0.174	0.326	

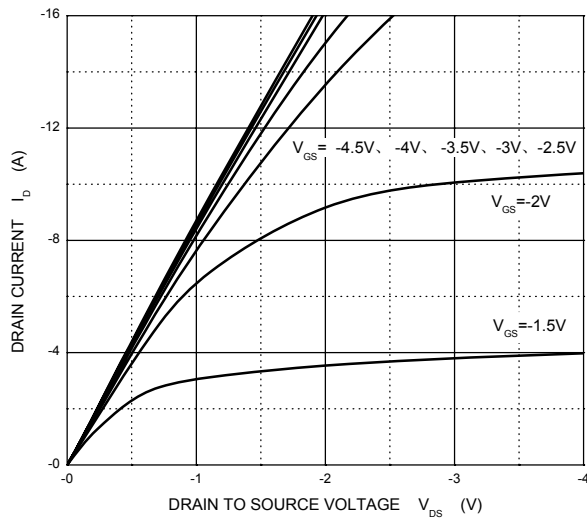
**ELECTRICAL CHARACTERISTICS(T<sub>a</sub>=25°C unless otherwise specified)**

Parameter	Symbol	Test Condition	Min	Typ	Max	Units
<b>Static</b>						
Drain-source breakdown voltage	V <sub>(BR)DSS</sub>	V <sub>GS</sub> = 0V, I <sub>D</sub> = -250μA	-12			V
Gate-source threshold voltage	V <sub>GS(th)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = -250μA	-0.5		-0.9	
Gate-source leakage	I <sub>GSS</sub>	V <sub>DS</sub> = 0V, V <sub>GS</sub> = ±8V			±100	nA
Zero gate voltage drain current	I <sub>DSS</sub>	V <sub>DS</sub> = -8V, V <sub>GS</sub> = 0V			-1	μA
Drain-source on-state resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -3.5A		30	45	mΩ
		V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -3A		40	60	
		V <sub>GS</sub> = -1.8V, I <sub>D</sub> = -2.0A		60	90	
Forward transconductance <sup>a</sup>	g <sub>fs</sub>	V <sub>DS</sub> = -5V, I <sub>D</sub> = -4.1A	6			S
<b>Dynamic</b>						
Input capacitance <sup>b,c</sup>	C <sub>iss</sub>	V <sub>DS</sub> = -4V, V <sub>GS</sub> = 0V, f = 1MHz		740		pF
Output capacitance <sup>b,c</sup>	C <sub>oss</sub>			290		
Reverse transfer capacitance <sup>b,c</sup>	C <sub>rss</sub>			190		
Total gate charge <sup>b</sup>	Q <sub>g</sub>	V <sub>DS</sub> = -4V, V <sub>GS</sub> = -4.5V, I <sub>D</sub> = -4.1A		7.8		nC
		V <sub>DS</sub> = -4V, V <sub>GS</sub> = -2.5V, I <sub>D</sub> = -4.1A		4.5		
Gate-source charge <sup>b</sup>	Q <sub>gs</sub>			1.2		
Gate-drain charge <sup>b</sup>	Q <sub>gd</sub>			1.6		
Gate resistance <sup>b,c</sup>	R <sub>g</sub>	f = 1MHz	1.4	7	14	Ω
Turn-on delay time <sup>b,c</sup>	t <sub>d(on)</sub>	V <sub>DD</sub> = -4V, R <sub>L</sub> = 1.2Ω, I <sub>D</sub> ≈ -3.3A, V <sub>GEN</sub> = -4.5V, R <sub>g</sub> = 1Ω		13	2	ns
Rise time <sup>b,c</sup>	t <sub>r</sub>			35	5	
Turn-off Delay time <sup>b,c</sup>	t <sub>d(off)</sub>			32	4	
Fall time <sup>b,c</sup>	t <sub>f</sub>			10	2	
Turn-on delay time <sup>b,c</sup>	t <sub>d(on)</sub>	V <sub>DD</sub> = -4V, R <sub>L</sub> = 1.2Ω, I <sub>D</sub> ≈ -3.3A, V <sub>GEN</sub> = -8V, R <sub>g</sub> = 1Ω		5	10	
Rise time <sup>b,c</sup>	t <sub>r</sub>			11	1	
Turn-off delay time <sup>b,c</sup>	t <sub>d(off)</sub>			22	3	
Fall time <sup>b,c</sup>	t <sub>f</sub>			16	2	
<b>Drain-source body diode characteristics</b>						
Continuous source-drain diode current	I <sub>S</sub>				-6	A
Pulse diode forward current <sup>a</sup>	I <sub>SM</sub>				-20	
Body diode voltage	V <sub>SD</sub>	I <sub>F</sub> = -3.3A			-1.2	V

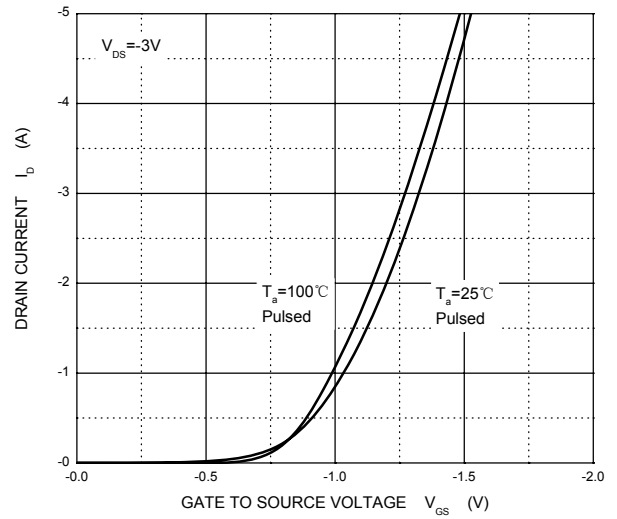
**Note :**

- a. Pulse Test ; Pulse Width ≤300μs, Duty Cycle ≤2%.
- b. Guaranteed by design, not subject to production testing.
- c. These parameters have no way to verify.

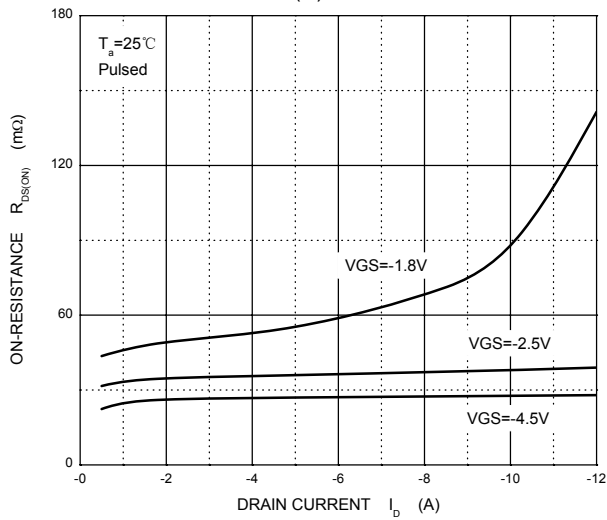
Output Characteristics



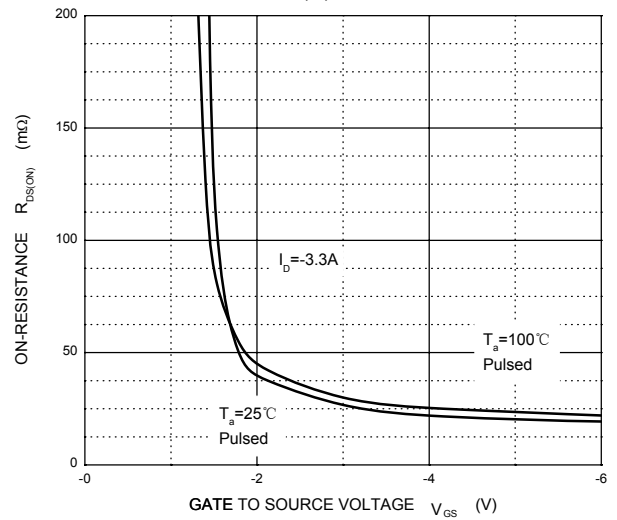
Transfer Characteristics



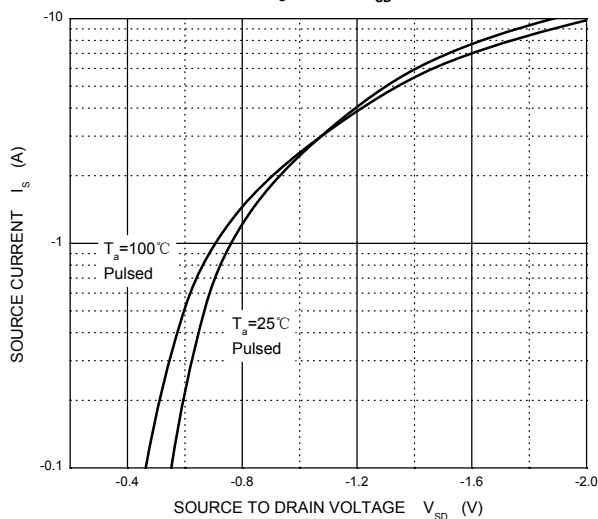
$R_{DS(ON)}$  —  $I_D$



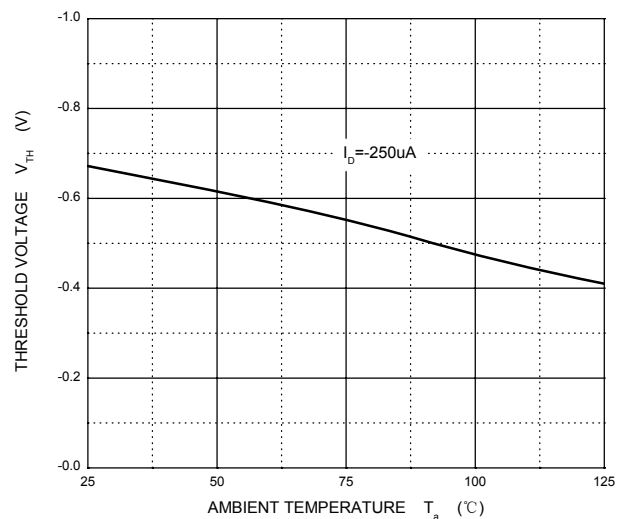
$R_{DS(ON)}$  —  $V_{GS}$



$I_S$  —  $V_{SD}$



Threshold Voltage





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Ordering Information :

Device	Packing
Part Number-TP	Tape&Reel: 3Kpcs/Reel

Note : Adding "-HF" suffix for halogen free, eg. Part Number-TP-HF

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- Подбор аналогов;
- Консультации по применению компонента;
- Поставка образцов и прототипов;
- Техническая поддержка проекта;
- Защита от снятия компонента с производства.



#### Как с нами связаться

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